

## Message Text

CONFIDENTIAL

PAGE 01 STATE 265711  
ORIGIN EB-08

INFO OCT-01 EUR-12 ISO-00 DODE-00 NSAE-00 USIA-06  
TRSE-00 ERDA-05 CIAE-00 COME-00 /032 R

DRAFTED BY EB/ITP/EWT - LROSS:JAS  
APPROVED BY EB/ITP/EWT - AREICHENBACH  
COMMERCE/OEA - RGAREL  
DEFENSE/OSD - DSCHROEDER  
RPE

-----103096 060405Z /73  
R 051923Z NOV 77  
FM SECSTATE WASHDC  
TO AMEMBASSY PARIS

C O N F I D E N T I A L STATE 265711

USOECD, EXCON

E.O. 11652: XGDS-1

TAGS: ESTC, COCOM, JA, PL

SUBJECT: JAPANESE HIGH POWER VOLTAGE SILICON DIODE MANUFAC-  
TURING PLANT TO POLAND--IL 1355

REF: COCOM DOC (77) 679

NO OBJECTION. CHRISTOPHER

CONFIDENTIAL

NNN

## Message Attributes

**Automatic Decaptioning:** X  
**Capture Date:** 01-Jan-1994 12:00:00 am  
**Channel Indicators:** n/a  
**Current Classification:** UNCLASSIFIED  
**Concepts:** SILICON, IL 1355, STRATEGIC TRADE CONTROLS  
**Control Number:** n/a  
**Copy:** SINGLE  
**Sent Date:** 05-Nov-1977 12:00:00 am  
**Decaption Date:** 01-Jan-1960 12:00:00 am  
**Decaption Note:**  
**Disposition Action:** RELEASED  
**Disposition Approved on Date:**  
**Disposition Case Number:** n/a  
**Disposition Comment:** 25 YEAR REVIEW  
**Disposition Date:** 22 May 2009  
**Disposition Event:**  
**Disposition History:** n/a  
**Disposition Reason:**  
**Disposition Remarks:**  
**Document Number:** 1977STATE265711  
**Document Source:** CORE  
**Document Unique ID:** 00  
**Drafter:** LROSS:JAS  
**Enclosure:** n/a  
**Executive Order:** X1  
**Errors:** N/A  
**Expiration:**  
**Film Number:** D770409-1006  
**Format:** TEL  
**From:** STATE  
**Handling Restrictions:** n/a  
**Image Path:**  
**ISecure:** 1  
**Legacy Key:** link1977/newtext/t19771191/aaaadacq.tel  
**Line Count:** 41  
**Litigation Code IDs:**  
**Litigation Codes:**  
**Litigation History:**  
**Locator:** TEXT ON-LINE, ON MICROFILM  
**Message ID:** 60799521-c288-dd11-92da-001cc4696bcc  
**Office:** ORIGIN EB  
**Original Classification:** CONFIDENTIAL  
**Original Handling Restrictions:** n/a  
**Original Previous Classification:** n/a  
**Original Previous Handling Restrictions:** n/a  
**Page Count:** 1  
**Previous Channel Indicators:** n/a  
**Previous Classification:** CONFIDENTIAL  
**Previous Handling Restrictions:** n/a  
**Reference:** n/a  
**Retention:** 0  
**Review Action:** RELEASED, APPROVED  
**Review Content Flags:**  
**Review Date:** 04-Mar-2005 12:00:00 am  
**Review Event:**  
**Review Exemptions:** n/a  
**Review Media Identifier:**  
**Review Release Date:** n/a  
**Review Release Event:** n/a  
**Review Transfer Date:**  
**Review Withdrawn Fields:** n/a  
**SAS ID:** 701531  
**Secure:** OPEN  
**Status:** NATIVE  
**Subject:** JAPANESE HIGH POWER VOLTAGE SILICON DIODE MANUFAC- TURING PLANT TO POLAND--IL 1355  
**TAGS:** ESTC, JA, PL, COCOM  
**To:** PARIS  
**Type:** TE  
**vdkgvwkey:** odb://SAS/SAS.dbo.SAS\_Docs/60799521-c288-dd11-92da-001cc4696bcc  
**Review Markings:**  
Margaret P. Grafeld  
Declassified/Released  
US Department of State  
EO Systematic Review  
22 May 2009  
**Markings:** Margaret P. Grafeld Declassified/Released US Department of State EO Systematic Review 22 May 2009